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# Dual Series High Voltage Switching Diode

# Product Preview MMBD1401ALT1G, MMBD1403ALT1G

#### Features

- Moisture Sensitivity Level: 1
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V <sub>R</sub>	250	Vdc
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	250	Vdc
Peak Forward Current	١ <sub>F</sub>	225	mAdc
Peak Forward Surge Current	I <sub>FM(surge)</sub>	625	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$	PD	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$	P <sub>D</sub>	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	−55 to +150	°C

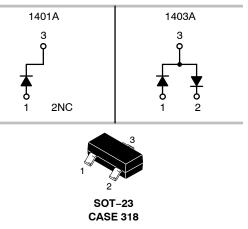
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR–5 = 1.0  $\times$  0.75  $\times$  0.062 in.
- 2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



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MARKING DIAGRAM



XXX= Specific Device Code MMBD1401: A29 MMBD1403: A32 M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBD1401ALT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBD1403ALT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

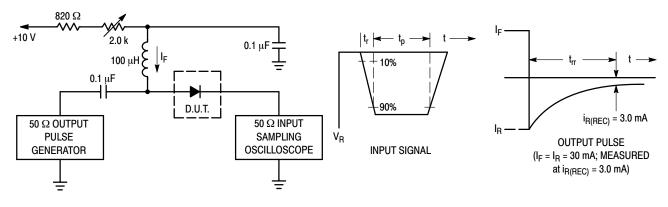
This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

## MMBD1401ALT1G, MMBD1403ALT1G

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS	·		·	•	
Reverse Voltage Leakage Current (V <sub>R</sub> = 200 Vdc) (V <sub>R</sub> = 175 Vdc)	I <sub>R</sub>		40 100	nA	
Reverse Breakdown Voltage (I <sub>BR</sub> = 100 μAdc)	V <sub>(BR)</sub>	250	-	V	
Forward Voltage (I <sub>F</sub> = 10 mA) (I <sub>F</sub> = 50 mA) (I <sub>F</sub> = 200 mA) (I <sub>F</sub> = 300 mA)	V <sub>F</sub>	- 760 - -	800 920 1.1 1.25	mV mV V V	
Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHz)	CD	-	5.0	pF	
Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 30 mA, I <sub>RR</sub> = 1.0 mA, R <sub>L</sub> = 100 $\Omega$ )	t <sub>rr</sub>	-	50	ns	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



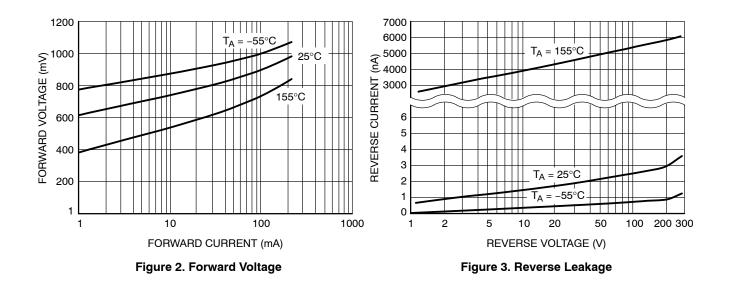
Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 30 mA. 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 30 mA.

3. t<sub>p</sub> » t<sub>rr</sub>

Figure 1. Recovery Time Equivalent Test Circuit

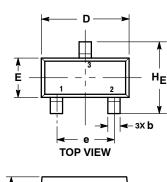
## MMBD1401ALT1G, MMBD1403ALT1G

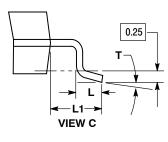
### **TYPICAL CHARACTERISTICS**



#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AS** 





NOTES

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 1. 2.

CONTROLLING DIMENSION: MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. З.

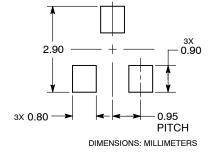
- MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4 PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
q	0.37	0.44	0.50	0.015	0.017	0.020
c	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
Г	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°
-				, v		10



SEE VIEW C **END VIEW** 

#### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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